

COMPLIANT

Power Resistor Thick Film Technology



LTO series are the extension of RTO types. We used the direct ceramic mounting design (no metal tab) of our RCH power resistors applied to semiconductor packages.

DIMENSIONS in millimeters

FEATURES

- 50 Watt at 25 °C Case Temperature Heatsink Mounted
- · Direct mounting ceramic on heatsink
- Broad Resistance Range: R010 to 550K
- Non Inductive
- TO-220 package: Compact and easy to mount
- · RoHS compliant
- · Isolated case



• Tolerance unless otherwise specified: ± 0.3 mm

MECHANICAL SPECIFICATIONS

Mechanical Protection	Molded			
Resistive Element	Thick Film			
Substrate	Alumina			
Connections	Tinned Copper			
Weight	2 g max.			
Mounting Torque	1 N-m			
DIMENSIONS				
Standard Package	TO-220 Isolated case			

ENVIRONMENTAL SPECIFICATIONS

Temperature Range Climatic Category - 55 °C to + 150 °C 55/155/56

ELECTRICAL SPECIFICATIONS

0.010 Ω to 550 k Ω		
± 1 % to ± 10 %		
Onto a heatsink		
50 W at + 25 °C (case temperature)		
Rтн (j-c): 2.5 °C/W		
free air:		
2.5 W at + 25 °C		
See Performance table		
± 150 ppm/°C		
250 V		
1500 VRMs - 1 minute - 10 mA max.		
$\geq 10^4 M\Omega$		
≤ 0.1 μH		
1.25 kΩ		



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PERFORMANCE				
TESTS	CONDITIONS	TYPICAL DRIFTS		
Momentary Overload	EN60115-1 1.5 Pr/5 s Us < 1.5 UL	± (0.5 % + 0.005 Ω)		
Rapid Temperature Change	EN60115-1 IEC 60068-2-14 Tests Na 5 cycles - 55 °C to + 155 °C			
Load Life	EN60115-1 1000 h Pr at + 25 °C	± (1 % + 0.005 Ω)		
Humidity (Steady State)	MIL STD 202 Method 103 B Cond. D	± (0.5 % + 0.005 Ω)		
Vibration	MIL STD 202 Method 204 Cond. D ± (0.2 % + 0.005)			
Terminal Strength	MIL STD 202 ± (0.2 % + 0.005 Ω)			
Shock	100G, MIL STD 202 Method 213 Cond. I	± (0.5 % + 0.005 Ω)		

SPECIAL FEATURES					
Resistance Values	≥ 0.010	≥ 0.015	≥ 0.1	≥ 0.5	
Tolerances	± 1 % at ± 10 %				
Typical Temperature Coefficient (- 55 °C/+ 150 °C)	vpical Temperature ± 900 ppm/°C ± 700 ppm/°C oefficient ± 900 ppm/°C ± 700 ppm/°C 55 °C/+ 150 °C) ************************************		± 250 ppm/°C	± 150 ppm/°C	

CHOICE OF THE HEATSINK

The user must choose according to the working conditions of the component (power, room temperature).

Maximum working temperature must not exceed 155 °C. The dissipated power is simply calculated by the following ratio:

$$\mathsf{P} = \frac{\Delta \mathsf{T}}{[\mathsf{R}_{\mathsf{TH}} (\mathsf{j-c}) + \mathsf{R}_{\mathsf{TH}} (\mathsf{c-a})]}$$
(1)

P: expressed in W

 ΔT : difference between maximum working temperature and room temperature.

RTH: (j-c): thermal resistance value measured between resistive layer and outer side of the resistor. It is the thermal resistance of the component.

 $R_{TH:}$ (c-a): thermal resistance value measured between outer side of the resistor and room temperature. It is the thermal resistance of the heatsink itself (type, shape), the quality of the fastening device, and the thermal resistance of the thermal compound.

Example:

RTH: (c-a) for LTO50 power rating 10 W at ambient temperature + 30 °C.

Thermal resistance RTH (j-c): 2.5 °C/W

Considering equation (1) we have:

$$\Delta T = 155 \text{ °C} - 30 \text{ °C} = 125 \text{ °C}$$

RTH (j-c) + RTH (c-a) = $\frac{\Delta T}{P} = \frac{125}{10} = 12.5 \text{ °C/W}$
RTH (c-a) = 12.5 °C/W - 2.5 °C/W = 10 °C/W

with a thermal grease R_{TH} (c - h) = 1 °C/W, we need a heat sink with R_{TH} (h - a) = 9 °C/W.

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OVERLOADS

In any case the applied voltage must be lower than the maximum overload voltage of 375V. The values indicated on the graph below are applicable to resistors in air or mounted onto a heatsink.



POWER RATING CHART

The temperature of the heatsink should be maintained within the limits specified.

To improve the thermal conductivity, surfaces in contact should be coated with a silicone grease and the torque applied on the screw for tightening should be around 1 Nm.



MARKING

Model, Style, Resistance Value (in Ω), Tolerance (in %), Manufacturing Date, VISHAY trademark.

PACKAGING

Tube of 50 units

ORDERING INFORMATION							
LTO MODEL	50 STYLE	F CONNECTIONS	100 k Ω RESISTANCE VALUE	±1% TOLERANCE	XXX CUSTOM DESIGN	TU50 PACKAGING	e3 LEAD (Pb)-FREE
				± 1 % ± 2 % ± 5 % ± 10 %	Optional on request: special TCR, shape etc.		
SAP PART NUMBERING GUIDELINES							
L SAP Part	T MODEL Number L	0 0 5T ST TO050F10002FTE3	5 0 F YLE CONNECTION 3	1 0 S RES	0 0 2 SISTANCE /ALUE	F T TOL PAC	E 3 K LEAD (Pb)-FREE



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